TEXAS INSTRUMENTS

SN54AHC125, SN74AHC125

SCLS256L – DECEMBER 1995 – REVISED NOVEMBER 2016

SNx4AHC125 Quadruple Bus Buffer Gates With 3-State Outputs

1 Features

- Operating Range: 2 V to 5.5 V
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Four Individual Output Enable Pins
- All Inputs Have Schmitt-Trigger Action

2 Applications

- Flow Meters
- Programmable Logic Controllers
- Power Over Ethernet (PoE)
- Motor Drives and Controls
- Electronic Point-of-Sale

3 Description

The SNx4AHC125 devices are quadruple bus buffer gates featuring independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable ($\overline{OE}$) input is high. When $\overline{OE}$ is low, the respective gate passes the data from the A input to its Y output.

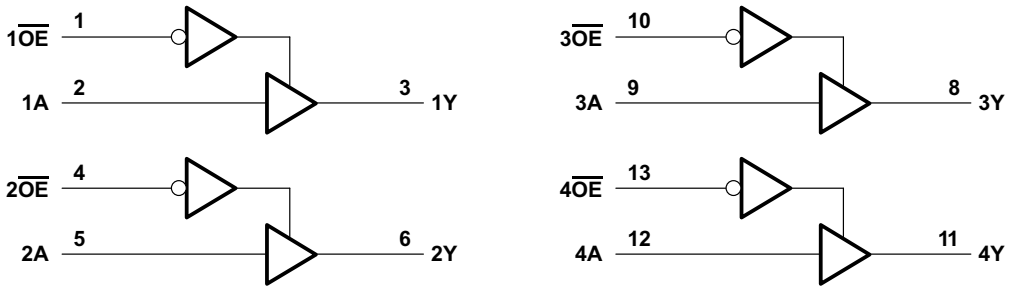
To ensure the high-impedance state during power up or power down, $\overline{OE}$ must be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Device Information(1)

PART NUMBER	PACKAGE (PINS)	BODY SIZE (NOM)
SNx4AHC125FK	LCCC (20)	8.89 mm 8.89 mm
SNx4AHC125DB	SSOP (14)	6.20 mm 5.30 mm
SNx4AHC125D	SOIC (14)	8.65 mm × 3.91 mm
SNx4AHC125NS	SO (14)	10.30 mm × 5.30 mm
SNx4AHC125W	CFP (14)	9.21 mm × 5.97 mm
SNx4AHC125DGV	TVSOP (14)	3.60 mm × 4.40 mm
SNx4AHC125PW	TSSOP (14)	5.00 mm × 4.40 mm
SNx4AHC125N	PDIP (14)	19.30 mm × 6.35 mm
SNx4AHC125RGY	VQFN (14)	3.50 mm × 3.50 mm
SNx4AHC125J	CDIP (14)	19.56 mm × 6.67 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Logic Diagram (Positive Logic)



Pin numbers shown are for the D, DB, DGV, J, N, NS, PW, RGY, and W packages.

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision K (June 2013) to Revision L **Page**

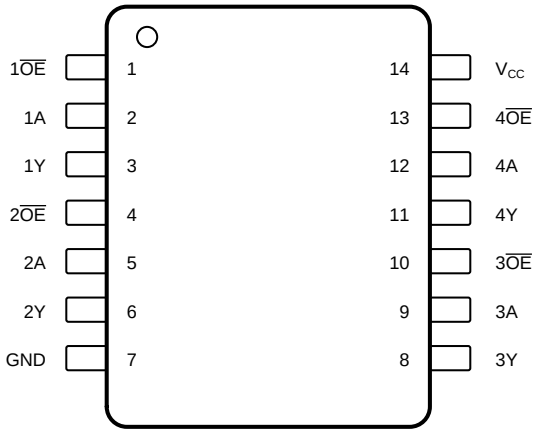
- Added *ESD Ratings* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section. ... 1
- Deleted *Ordering Information* table; see *Package Option Addendum* at the end of the data sheet ... 1
- Changed Package thermal impedance, $R_{\theta JA}$, value in *Thermal Information* table From: 86°C/W To: 92.6°C/W (D), From: 96°C/W To: 107.3°C/W (DB), From: 127°C/W To: 134.6°C/W (DGV), From: 80°C/W To: 56.3°C/W (N), From: 76°C/W To: 89.9°C/W (NS), and From: 113°C/W To: 121.5°C/W (PW) ... 6

Changes from Revision J (December 1995) to Revision K **Page**

- Changed document format from Quicksilver to DocZone ... 1
- Extended operating temperature range to 125°C ... 5

5 Pin Configuration and Functions

D, DB, DGV, N, NS, J, W, or PW Package
14-Pin SOIC, SSOP, TVSOP, PDIP, SO, CDIP, CFP, or TSSOP
Top View



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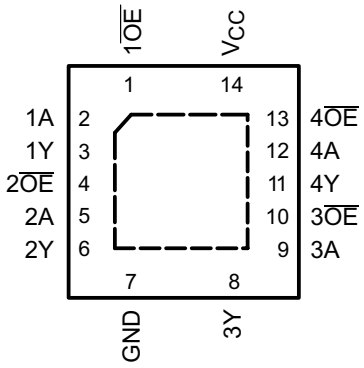
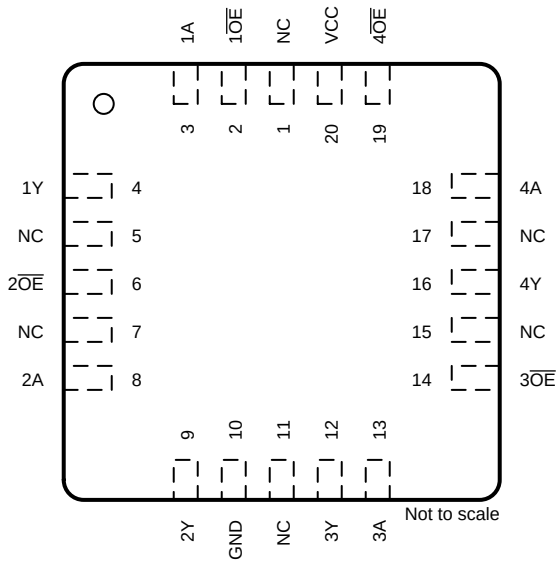
RGY Package
14-Pin VQFN
Top View



FK Package
20-Pin LCCC
Top View



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Pin Functions

PIN			I/O	DESCRIPTION
NAME	SOIC, SSOP, TVSOP, PDIP, SO, CDIP, CFP, TSSOP, VQFN	LCCC		
$1\overline{OE}$	1	2	I	Output enable for gate 1
1A	2	3	I	Gate 1 input
1Y	3	4	O	Gate 1 output
$2\overline{OE}$	4	6	I	Output enable for gate 2
2A	5	8	I	Gate 2 input
2Y	6	9	O	Gate 2 output
$3\overline{OE}$	10	14	I	Output enable for gate 3
3A	9	13	I	Gate 3 input
3Y	8	12	O	Gate 3 output
$4\overline{OE}$	13	19	I	Output enable for gate 4
4A	12	18	I	Gate 4 input
4Y	11	16	O	Gate 4 output
GND	7	10	—	Ground pin
NC	—	1, 5, 7, 11, 15, 17	—	No internal connection
V_{CC}	14	20	—	Power pin

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Supply voltage		–0.5	7	V
Input voltage(2)		–0.5	7	V
Output voltage(2)		–0.5	V_{CC} + 0.5	V
Input clamp current	V_I < 0		–20	mA
Output clamp current	V_O < 0 or V_O > V_{CC}		±20	mA
Continuous output current	V_O = 0 to V_{CC}		±25	mA
Continuous current through V_{CC} or GND			±50	mA
Virtual operating junction temperature, T_J			150	°C
Storage temperature, T_{stg}		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±1500	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		2	5.5	V
V_{IH}	High-level input voltage	V_{CC} = 2 V	1.5		V
		V_{CC} = 3V	2.1		
		V_{CC} = 5.5 V	3.85		
V_{IL}	Low-level Input voltage	V_{CC} = 2 V		0.5	V
		V_{CC} = 3 V		0.9	
		V_{CC} = 5.5 V		1.65	
V_I	Input voltage		0	5.5	V
V_O	Output voltage		0	V_{CC}	V
I_{OH}	High-level output current	V_{CC} = 2 V		–50	µA
		V_{CC} = 3.3 V ±0.3 V		–4	mA
		V_{CC} = 5 V ±0.5 V		–8	
I_{OL}	Low-level output current	V_{CC} = 2 V		50	µA
		V_{CC} = 3.3 V ±0.3 V		4	mA
		V_{CC} = 5 V ±0.5 V		8	
$\Delta t/\Delta v$	Input Transition rise or fall rate	V_{CC} = 3.3 V ±0.3 V		100	ns/V
		V_{CC} = 5 V ±0.5 V		20	
T_A	Operating free-air temperature		–40	125	°C

6.4 Thermal Information

THERMAL METRIC(1)		SNx4AHC125							UNIT
		D (SOIC)	DB (SSOP)	NS (SO)	DGV (TVSOP)	PW (TSSOP)	N (PDIP)	RGY (VQFN)	
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	92.6	107.3	89.9	134.6	121.5	56.3	55.1	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	52.7	59.3	47.7	53.9	50.2	43.9	52.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	46.8	54.7	48.6	63.8	63.2	36.1	30.9	°C/W
ψ_{JT}	Junction-to-top characterization parameter	19.7	24	17.5	6.3	6.1	29.2	2.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	46.6	54.1	48.3	63.2	62.7	36	31	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	—	—	—	—	—	—	12.7	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
V_{OH}	I_{OH} = –50 µA	V_{CC} = 2 V	T_A = 25°C	1.9	2		V
			T_A = –55°C to 125°C (SN54AHC125)	1.9			
			T_A = –40°C to 85°C (SN74AHC125)	1.9			
			T_A = –40°C to 125°C (recommended SN74AHC125)	1.9			
		V_{CC} = 3 V	T_A = 25°C	2.9	3		
			T_A = –55°C to 125°C (SN54AHC125)	2.9			
			T_A = –40°C to 85°C (SN74AHC125)	2.9			
			T_A = –40°C to 125°C (recommended SN74AHC125)	2.9			
		V_{CC} = 4.5 V	T_A = 25°C	4.4	4.5		
			T_A = –55°C to 125°C (SN54AHC125)	4.4			
			T_A = –40°C to 85°C (SN74AHC125)	4.4			
			T_A = –40°C to 125°C (recommended SN74AHC125)	4.4			
	I_{OH} = –4 mA and V_{CC} = 3 V		T_A = 25°C	2.58			
			T_A = –55°C to 125°C (SN54AHC125)	2.48			
			T_A = –40°C to 85°C (SN74AHC125)	2.48			
			T_A = –40°C to 125°C (recommended SN74AHC125)	2.48			
	I_{OH} = –8 mA and V_{CC} = 4.5 V		T_A = 25°C	3.94			
			T_A = –55°C to 125°C (SN54AHC125)	3.8			
			T_A = –40°C to 85°C (SN74AHC125)	3.8			
			T_A = –40°C to 125°C (recommended SN74AHC125)	3.8			

Electrical Characteristics (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
V_{OL}	I_{OL} = 50 µA	V_{CC} = 2 V	T_A = 25°C			0.1	V
			T_A = –55°C to 125°C (SN54AHC125)			0.1	
			T_A = –40°C to 85°C (SN74AHC125)			0.1	
			T_A = –40°C to 125°C (recommended SN74AHC125)			0.1	
		V_{CC} = 3 V	T_A = 25°C			0.1	
			T_A = –55°C to 125°C (SN54AHC125)			0.1	
			T_A = –40°C to 85°C (SN74AHC125)			0.1	
			T_A = –40°C to 125°C (recommended SN74AHC125)			0.1	
		V_{CC} = 4.5 V	T_A = 25°C			0.1	
			T_A = –55°C to 125°C (SN54AHC125)			0.1	
			T_A = –40°C to 85°C (SN74AHC125)			0.1	
			T_A = –40°C to 125°C (recommended SN74AHC125)			0.1	
	I_{OH} = 4 mA and V_{CC} = 3 V		T_A = 25°C			0.36	
			T_A = –55°C to 125°C (SN54AHC125)			0.5	
			T_A = –40°C to 85°C (SN74AHC125)			0.44	
			T_A = –40°C to 125°C (recommended SN74AHC125)			0.5	
	I_{OH} = 8 mA and V_{CC} = 4.5 V		T_A = 25°C			0.36	
			T_A = –55°C to 125°C (SN54AHC125)			0.5	
			T_A = –40°C to 85°C (SN74AHC125)			0.44	
			T_A = –40°C to 125°C (recommended SN74AHC125)			0.5	
I_I	V_I = 5.5 V or GND and V_{CC} = 0 V to 5.5 V		T_A = 25°C			±0.1	µA
			T_A = –55°C to 125°C (SN54AHC125)			±1 (1)	
			T_A = –40°C to 85°C (SN74AHC125)			±1	
			T_A = –40°C to 125°C (recommended SN74AHC125)			±1	
I_{OZ}	V_O = V_{CC} or GND and V_{CC} = 5.5 V		T_A = 25°C			±0.25	µA
			T_A = –55°C to 125°C (SN54AHC125)			±2.5	
			T_A = –40°C to 85°C (SN74AHC125)			±2.5	
			T_A = –40°C to 125°C (recommended SN74AHC125)			±2.5	
I_{CC}	V_I = V_{CC} or GND, I_O = 0, and V_{CC} = 5.5 V		T_A = 25°C			4	µA
			T_A = –55°C to 125°C (SN54AHC125)			40	
			T_A = –40°C to 85°C (SN74AHC125)			40	
			T_A = –40°C to 125°C (recommended SN74AHC125)			40	
C_i	V_I = V_{CC} or GND and V_{CC} = 5 V		T_A = 25°C		4	10	pF
			T_A = –40°C to 85°C (SN74AHC125)			10	

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested at V_{CC} = 0 V.

6.6 Switching Characteristics: V_{CC} = 3.3 V ±0.3 V

over recommended operating free-air temperature range and V_{CC} = 3.3 V ±0.3 V (unless otherwise noted; see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		MIN	TYP	MAX	UNIT
t_{PHL}, t_{PLH}	A	Y	C_L = 15 pF	T_A = 25°C		5.6(1)	8(1)	ns
				T_A = –55°C to 125°C (SN54AHC125)	1(1)		9.5(1)	
				T_A = –40°C to 85°C (SN74AHC125)	1		9.5	
				T_A = –40°C to 125°C (recommended SN74AHC125)	1		9.5	
t_{PZL}, t_{PZH}	$\overline{OE}$	Y	C_L = 15 pF	T_A = 25°C		5.4(1)	8(1)	ns
				T_A = –55°C to 125°C (SN54AHC125)	1(1)		9.5(1)	
				T_A = –40°C to 85°C (SN74AHC125)			9.5	
				T_A = –40°C to 125°C (recommended SN74AHC125)			9.5	
t_{PLZ}, t_{PHZ}	$\overline{OE}$	Y	C_L = 15 pF	T_A = 25°C		7.0(1)	9.7(1)	ns
				T_A = –55°C to 125°C (SN54AHC125)	1(1)		11.5(1)	
				T_A = –40°C to 85°C (SN74AHC125)	1(1)		11.5(1)	
				T_A = –40°C to 125°C (recommended SN74AHC125)	1(1)		11.5(1)	
t_{PHL}, t_{PLH}	A	Y	C_L = 50 pF	T_A = 25°C		8.1	11.5	ns
				T_A = –55°C to 125°C (SN54AHC125)	1		13	
				T_A = –40°C to 85°C (SN74AHC125)	1		13	
				T_A = –40°C to 125°C (recommended SN74AHC125)	1		13	
t_{PZL}, t_{PZH}	$\overline{OE}$	Y	C_L = 50 pF	T_A = 25°C		7.9	11.5	ns
				T_A = –55°C to 125°C (SN54AHC125)	1		13	
				T_A = –40°C to 85°C (SN74AHC125)	1		13	
				T_A = –40°C to 125°C (recommended SN74AHC125)	1		13	
t_{PLZ}, t_{PHZ}	$\overline{OE}$	Y	C_L = 50 pF	T_A = 25°C		9.5	13.2	ns
				T_A = –55°C to 125°C (SN54AHC125)	1		15	
				T_A = –40°C to 85°C (SN74AHC125)	1		15	
				T_A = –40°C to 125°C (recommended SN74AHC125)	1		15	
tsk(o)	$\overline{OE}$	Y	C_L = 50 pF	T_A = 25°C			1.5(2)	ns
				T_A = –40°C to 85°C (SN74AHC125)			1.5	

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.
(2) On products compliant to MIL-PRF-38535, this parameter does not apply.

6.7 Switching Characteristics: V_{CC} = 5 V ±0.5 V

over recommended operating free-air temperature range and V_{CC} = 5 V ±0.5 V (unless otherwise noted; see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		MIN	TYP	MAX	UNIT
t_{PLH}, t_{PHL}	A	Y	C_L = 15 pF	T_A = 25°C		3.8(1)	5.5(1)	ns
				T_A = –55°C to 125°C (SN54AHC125)	1(1)		6.5(1)	
				T_A = –40°C to 85°C (SN74AHC125)	1		6.5	
				T_A = –40°C to 125°C (recommended SN74AHC125)	1		6.5	
t_{PZH}, t_{PZL}	$\overline{OE}$	Y	C_L = 15 pF	T_A = 25°C		3.6(1)	5.1(1)	ns
				T_A = –55°C to 125°C (SN54AHC125)	1(1)		6(1)	
				T_A = –40°C to 85°C (SN74AHC125)	1		6	
				T_A = –40°C to 125°C (recommended SN74AHC125)	1		6	
t_{PHZ}, t_{PLZ}	$\overline{OE}$	Y	C_L = 15 pF	T_A = 25°C		4.6(1)	6.8(1)	ns
				T_A = –55°C to 125°C (SN54AHC125)	1(1)		8(1)	
				T_A = –40°C to 85°C (SN74AHC125)	1(1)		8(1)	
				T_A = –40°C to 125°C (recommended SN74AHC125)	1(1)		8(1)	
t_{PLH}, t_{PHL}	A	Y	C_L = 50 pF	T_A = 25°C		5.3	7.5	ns
				T_A = –55°C to 125°C (SN54AHC125)	1		8.5	
				T_A = –40°C to 85°C (SN74AHC125)	1		8.5	
				T_A = –40°C to 125°C (recommended SN74AHC125)	1		8.5	
t_{PZH}, t_{PZL}	$\overline{OE}$	Y	C_L = 50 pF	T_A = 25°C		5.1	7.1	ns
				T_A = –55°C to 125°C (SN54AHC125)	1		8	
				T_A = –40°C to 85°C (SN74AHC125)	1		8	
				T_A = –40°C to 125°C (recommended SN74AHC125)	1		8	
t_{PHZ}, t_{PLZ}	$\overline{OE}$	Y	C_L = 50 pF	T_A = 25°C		6.1	8.8	ns
				T_A = –55°C to 125°C (SN54AHC125)	1		10	
				T_A = –40°C to 85°C (SN74AHC125)	1		10	
				T_A = –40°C to 125°C (recommended SN74AHC125)	1		10	
tsk(o)	$\overline{OE}$	Y	C_L = 50 pF	T_A = 25°C			1(2)	ns
				T_A = –40°C to 85°C (SN74AHC125)			1	

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.
(2) On products compliant to MIL-PRF-38535, this parameter does not apply.

6.8 Noise Characteristics

V_{CC} = 5 V, C_L = 50 pF, and T_A = 25°C(1)

PARAMETER		MIN	MAX	UNIT
$V_{OL(P)}$	Quiet output, maximum dynamic (V_{OL})		0.8	V
$V_{OL(V)}$	Quiet output, minimum dynamic (V_{OL})		–0.8	V
$V_{OH(V)}$	Quiet output, minimum dynamic (V_{OH})	4.4		V
$V_{IH(D)}$	High-level dynamic input voltage	3.5		V
$V_{IL(D)}$	Low-level dynamic input voltage		1.5	V

(1) Characteristics are for surface-mount packages only.

6.9 Operating Characteristics

V_{CC} = 5 V and T_A = 25°C

PARAMETER		TEST CONDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	No load and f = 1 MHz	9.5	pF

6.10 Typical Characteristics

Figure 1 shows I_{CC} for varying V_{IN} values when V_{CC} is 5 V ±0.5 V and T_A = 25°C.

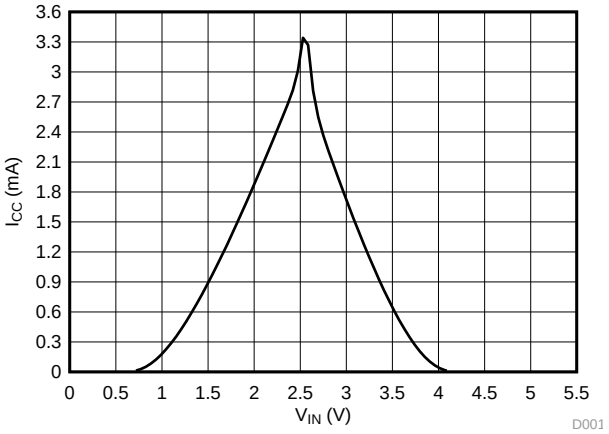
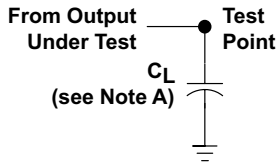
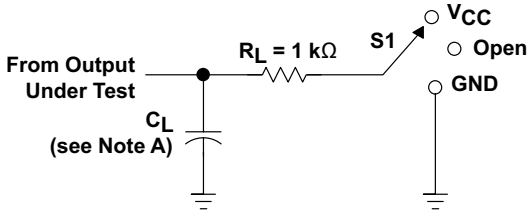


Figure 1. V_{IN} vs I_{CC}

7 Parameter Measurement Information

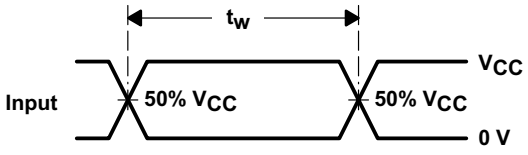


LOAD CIRCUIT FOR
TOTEM-POLE OUTPUTS

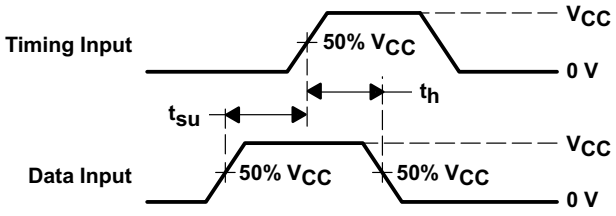


LOAD CIRCUIT FOR
3-STATE AND OPEN-DRAIN OUTPUTS

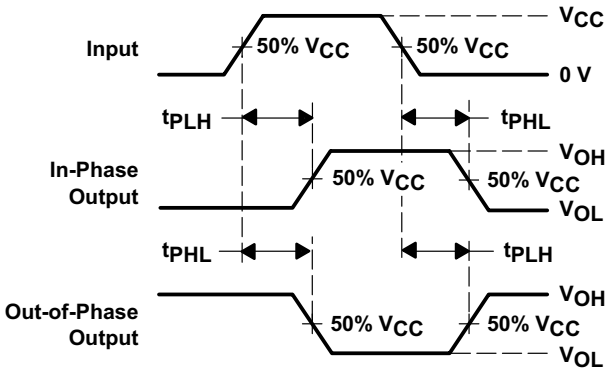
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{CC}
t_{PHZ}/t_{PZH}	GND
Open Drain	V_{CC}



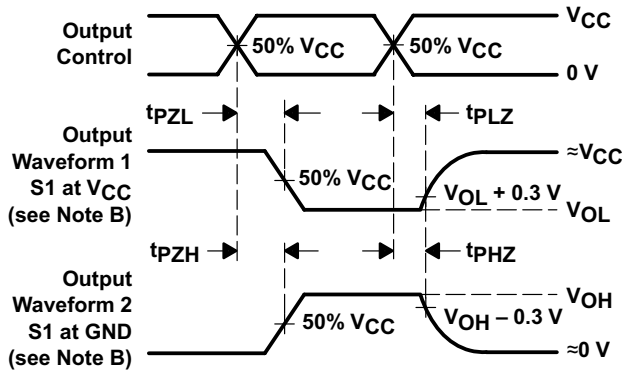
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_r ≤ 3 ns, t_f ≤ 3 ns.

D. The outputs are measured one at a time with one input transition per measurement.

E. All parameters and waveforms are not applicable to all devices.

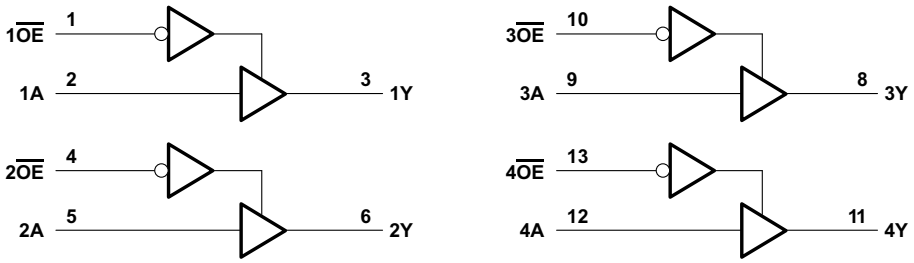
Figure 2. Load Circuit and Voltage Waveforms

8 Detailed Description

8.1 Overview

The SNx4AHC125 devices have four integrated bus buffer gates. Each gate can be individually controlled from their respective output enable pins or tied together and controlled simultaneously. This allows for control of up to four different lines from one device. Often times a microcontroller have multiple function options for a single pin. By using GPIO pins to enable specific buffers, the SNx4AHC125 can act as a multiplexer to select a specific data line depending on what pin function is selected on the microcontroller. At the same time, the lines that are not selected are isolated from the pin.

8.2 Functional Block Diagram



Pin numbers shown are for the D, DB, DGV, J, N, NS, PW, RGY, and W packages.

8.3 Feature Description

Each buffer has its own output enable. This allows for control of each buffer individually. When the output enable is LOW, the input is passed to the output. When the output enable is HIGH, the output is high impedance. This feature is useful in applications that might require isolation.

8.4 Device Functional Modes

Table 1 lists the functional modes of the SNx4AHC125.

Table 1. Function Table (Each Buffer)

INPUTS		OUTPUT
$\overline{OE}$	A	Y
L	H	H
L	L	L
H	X	Z

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The wide operating range of the SNx4AHC125 devices allows for implementation into a variety of applications. In addition to the wide operating range, these devices differentiate from similar devices because they have four buffers that can be individually controlled through their independent output enable ($\overline{OE}$) pins. Each buffer is either enabled and passes data from A to Y, or disabled and set to a high-impedance state.

9.2 Typical Application

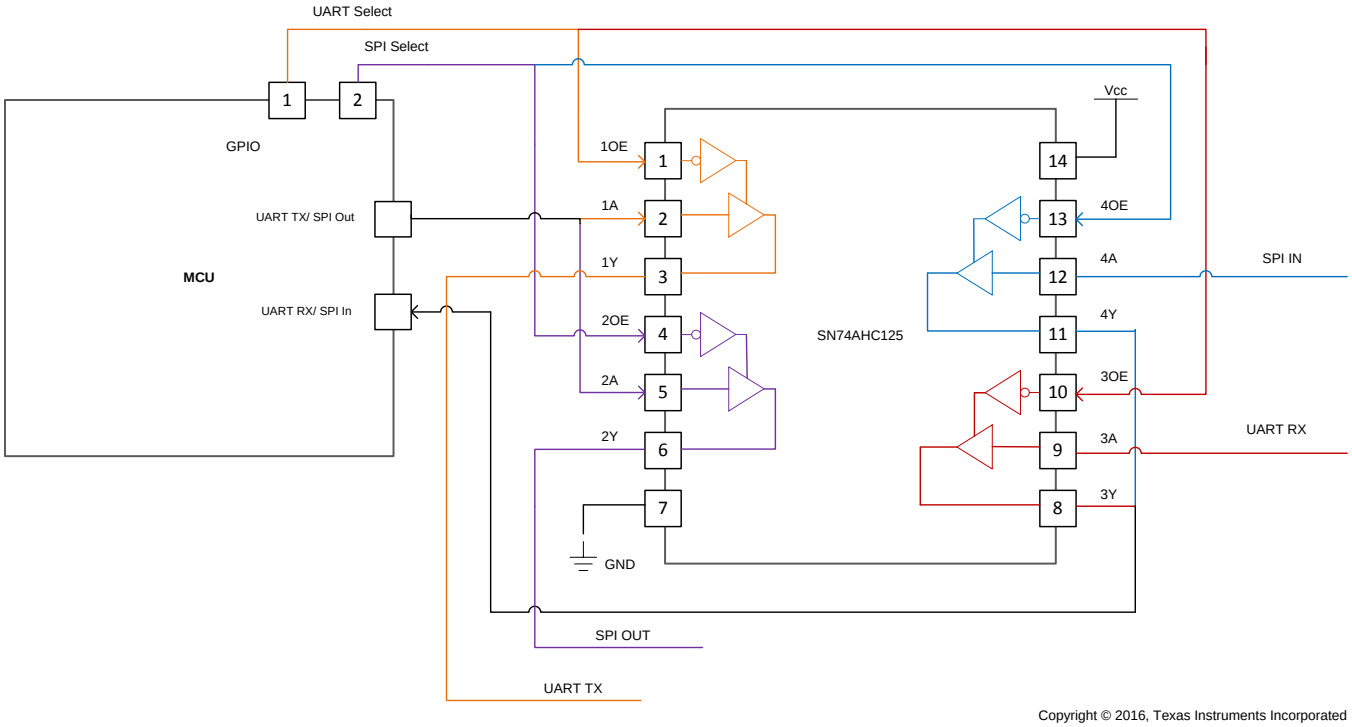


Figure 3. Digital MUX

9.2.1 Design Requirements

It is best to set V_{CC} for the SN74AHC125 to the same level as the microcontroller logic levels. This allows for optimal performance. The SN74AHC125 can safely handle input levels from –0.5 V to 7 V. However, if the logic levels that are being received vary from the V_{CC} level of the device then errors can occur. For example, if V_{CC} is 5.5 V then the minimum high-level input voltage (V_{IH}) level is 3.85 V. This means if the microcontroller is sending a HIGH signal, but HIGH = 3.3 V, it would be too low a level for the SNx4AHC125 to register it as what it must be. In this case V_{CC} would need to be lowered in order to lower the V_{IH} minimum. The opposite is also true for low-level input voltage (V_{IL}). If VCC is set to 2 V, then V_{IL} maximum is 0.5 V. Depending on the microcontroller logic levels, a LOW signal may not go low enough for the SNx4AHC125 to register it.

Typical Application (continued)

9.2.2 Detailed Design Procedure

1. Recommended Input Conditions:
   - For V_{IH} and V_{IL} levels at varying V_{CC}, see *Recommended Operating Conditions*.
   - Be mindful of rise time and fall time specifications for the output enable pins to ensure that the right buffers are enabled and the others are disabled in time. This minimizes interference on the microcontroller pin and to exterior circuitry. See *Switching Characteristics: V_{CC} = 3.3 V ±0.3 V* and *Switching Characteristics: V_{CC} = 5 V ±0.5 V* table for more details.
2. Recommended Output Conditions:
   - Load currents must not exceed I_O maximum per output and must not exceed continuous current through V_{CC} or GND total current for the part. These limits are located in the *Absolute Maximum Ratings*.
   - Outputs must not be pulled above V_{CC}.

9.2.3 Application Curves

Typical device at 25°C

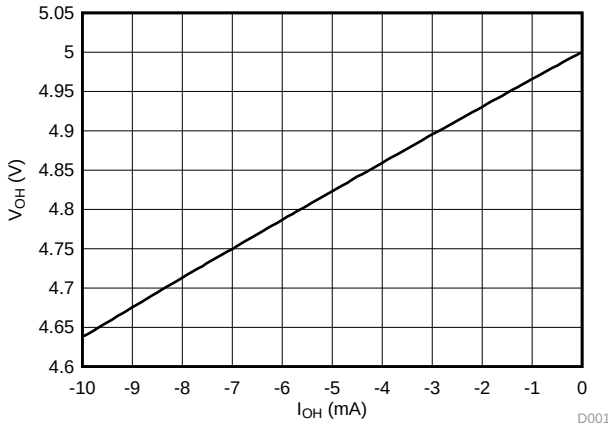


Figure 4. I_{OH} vs V_{OH}

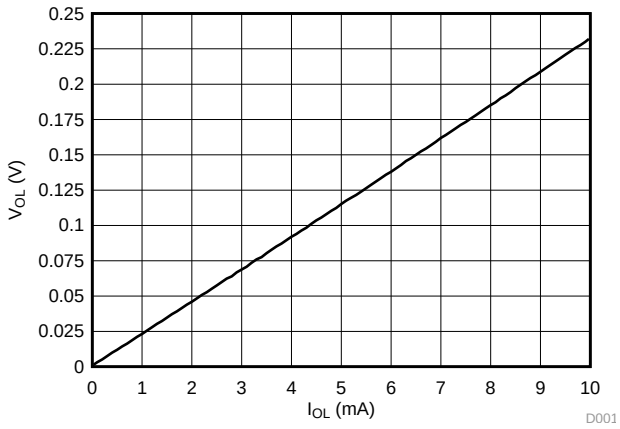


Figure 5. I_{OL} vs V_{OL}

10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*.

Each V_{CC} pin must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1-µF capacitor is recommended and if there are multiple V_{CC} pins then a 0.01-µF or 0.022-µF capacitor is recommended for each power pin. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor must be installed as close to the power pin as possible for best results.

11 Layout

11.1 Layout Guidelines

When using multiple bit logic devices, inputs must not ever float. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, they are tied to GND or V_{CC} (whichever make more sense or is more convenient).

11.2 Layout Example

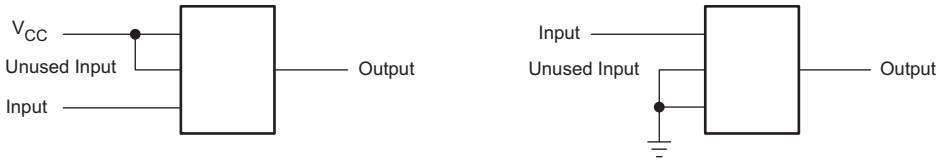


Figure 6. Layout Diagram

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

Implications of Slow or Floating CMOS Inputs (SCBA004)

12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54AHC125	Click here	Click here	Click here	Click here	Click here
SN74AHC125	Click here	Click here	Click here	Click here	Click here

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community ***TI's Engineer-to-Engineer (E2E) Community.*** Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support ***TI's Design Support*** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.5 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

12.6 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.7 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9686801Q2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686801Q2A SNJ54AHC125FK	Samples
5962-9686801QCA	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686801QCA SNJ54AHC125J	Samples
5962-9686801QDA	ACTIVE	CFP	W	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686801QDA SNJ54AHC125W	Samples
SN74AHC125D	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC125	Samples
SN74AHC125DBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA125	Samples
SN74AHC125DG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC125	Samples
SN74AHC125DGVR	ACTIVE	TVSOP	DGV	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA125	Samples
SN74AHC125DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC125	Samples
SN74AHC125DRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC125	Samples
SN74AHC125N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHC125N	Samples
SN74AHC125NE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHC125N	Samples
SN74AHC125NSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC125	Samples
SN74AHC125PW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA125	Samples
SN74AHC125PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA125	Samples
SN74AHC125PWRE4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA125	Samples
SN74AHC125PWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA125	Samples
SN74AHC125RGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	HA125	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AHC125RGYRG4	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	HA125	Samples
SNJ54AHC125FK	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686801Q2A SNJ54AHC 125FK	Samples
SNJ54AHC125J	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686801QCA SNJ54AHC125J	Samples
SNJ54AHC125W	ACTIVE	CFP	W	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686801QDA SNJ54AHC125W	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54AHC125, SN74AHC125 :

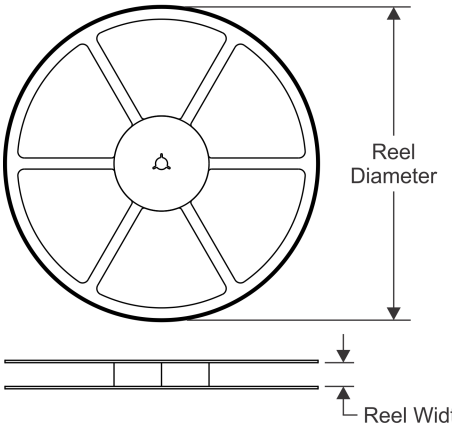
- Catalog : SN74AHC125
- Automotive : SN74AHC125-Q1, SN74AHC125-Q1
- Enhanced Product : SN74AHC125-EP, SN74AHC125-EP
- Military : SN54AHC125

NOTE: Qualified Version Definitions:

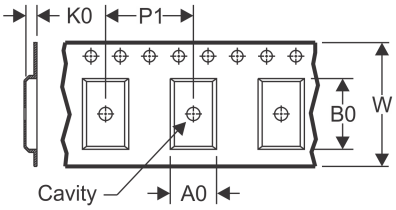
- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

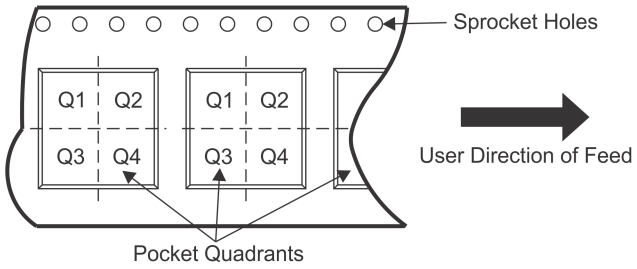


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

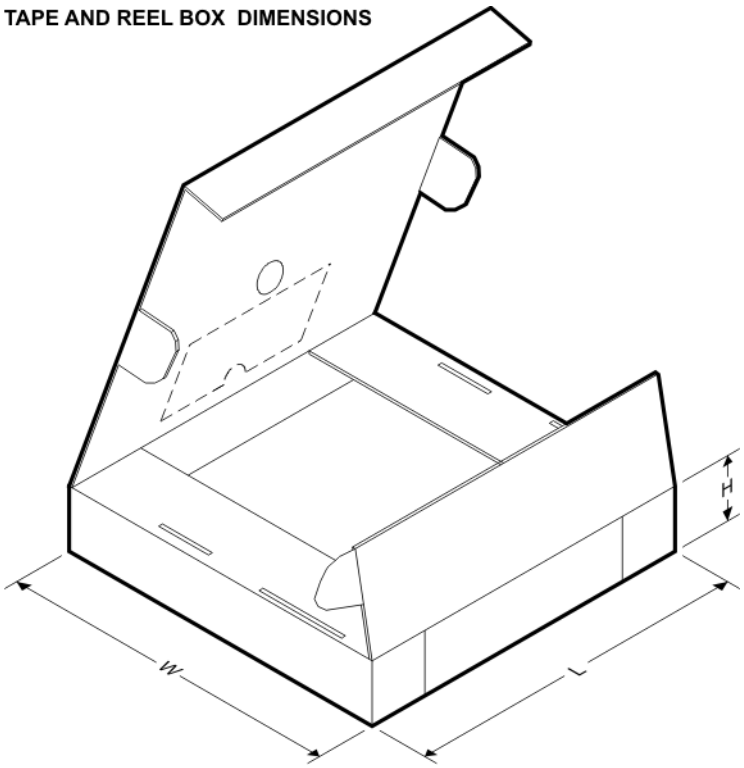
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC125DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74AHC125DGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74AHC125DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHC125DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHC125NSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74AHC125PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC125RGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1

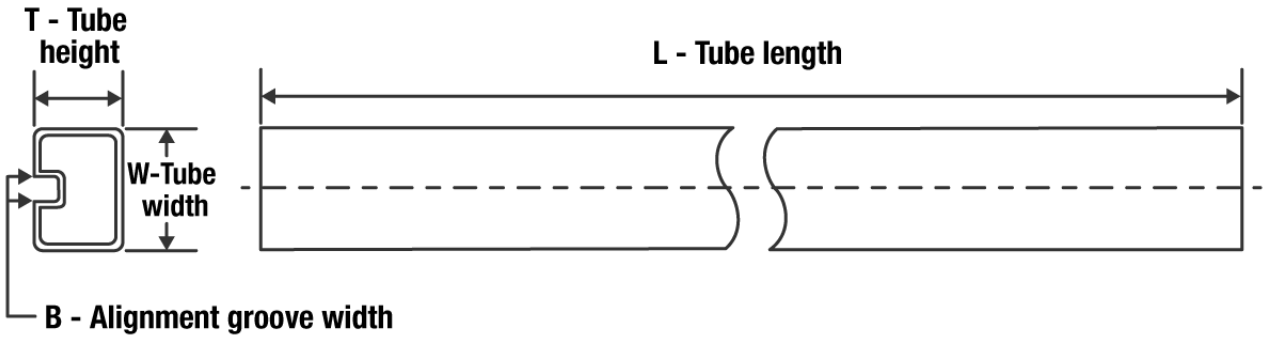
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC125DBR	SSOP	DB	14	2000	853.0	449.0	35.0
SN74AHC125DGVR	TVSOP	DGV	14	2000	853.0	449.0	35.0
SN74AHC125DR	SOIC	D	14	2500	853.0	449.0	35.0
SN74AHC125DR	SOIC	D	14	2500	340.5	336.1	32.0
SN74AHC125NSR	SO	NS	14	2000	853.0	449.0	35.0
SN74AHC125PWR	TSSOP	PW	14	2000	853.0	449.0	35.0
SN74AHC125RGYR	VQFN	RGY	14	3000	853.0	449.0	35.0

TUBE

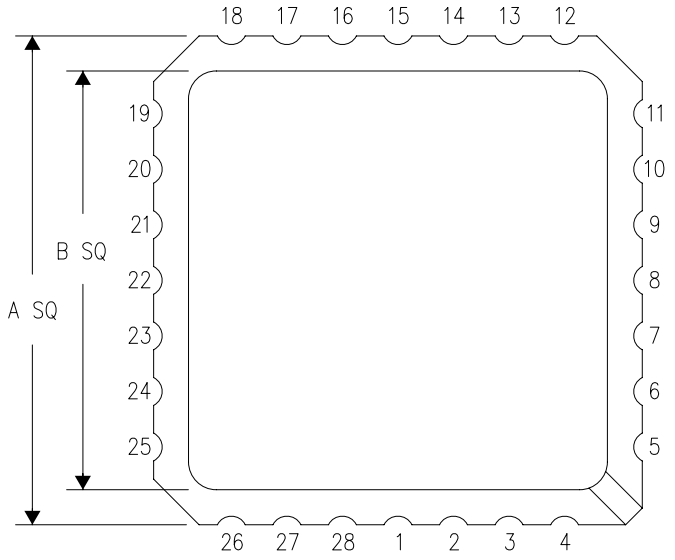


*All dimensions are nominal

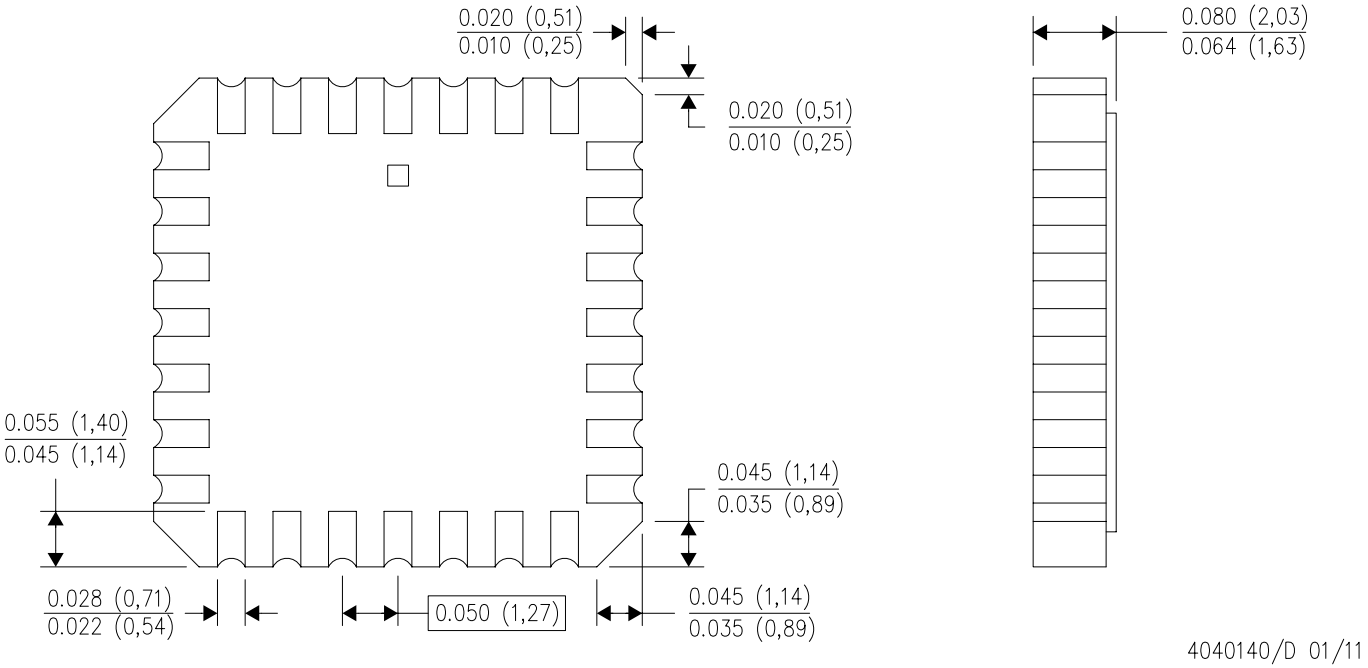
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9686801Q2A	FK	LCCC	20	1	506.98	12.06	2030	NA
SN74AHC125D	D	SOIC	14	50	506.6	8	3940	4.32
SN74AHC125DG4	D	SOIC	14	50	506.6	8	3940	4.32
SN74AHC125N	N	PDIP	14	25	506	13.97	11230	4.32
SN74AHC125N	N	PDIP	14	25	506	13.97	11230	4.32
SN74AHC125NE4	N	PDIP	14	25	506	13.97	11230	4.32
SN74AHC125NE4	N	PDIP	14	25	506	13.97	11230	4.32
SN74AHC125PW	PW	TSSOP	14	90	530	10.2	3600	3.5
SNJ54AHC125FK	FK	LCCC	20	1	506.98	12.06	2030	NA

FK (S–CQCC–N**) LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



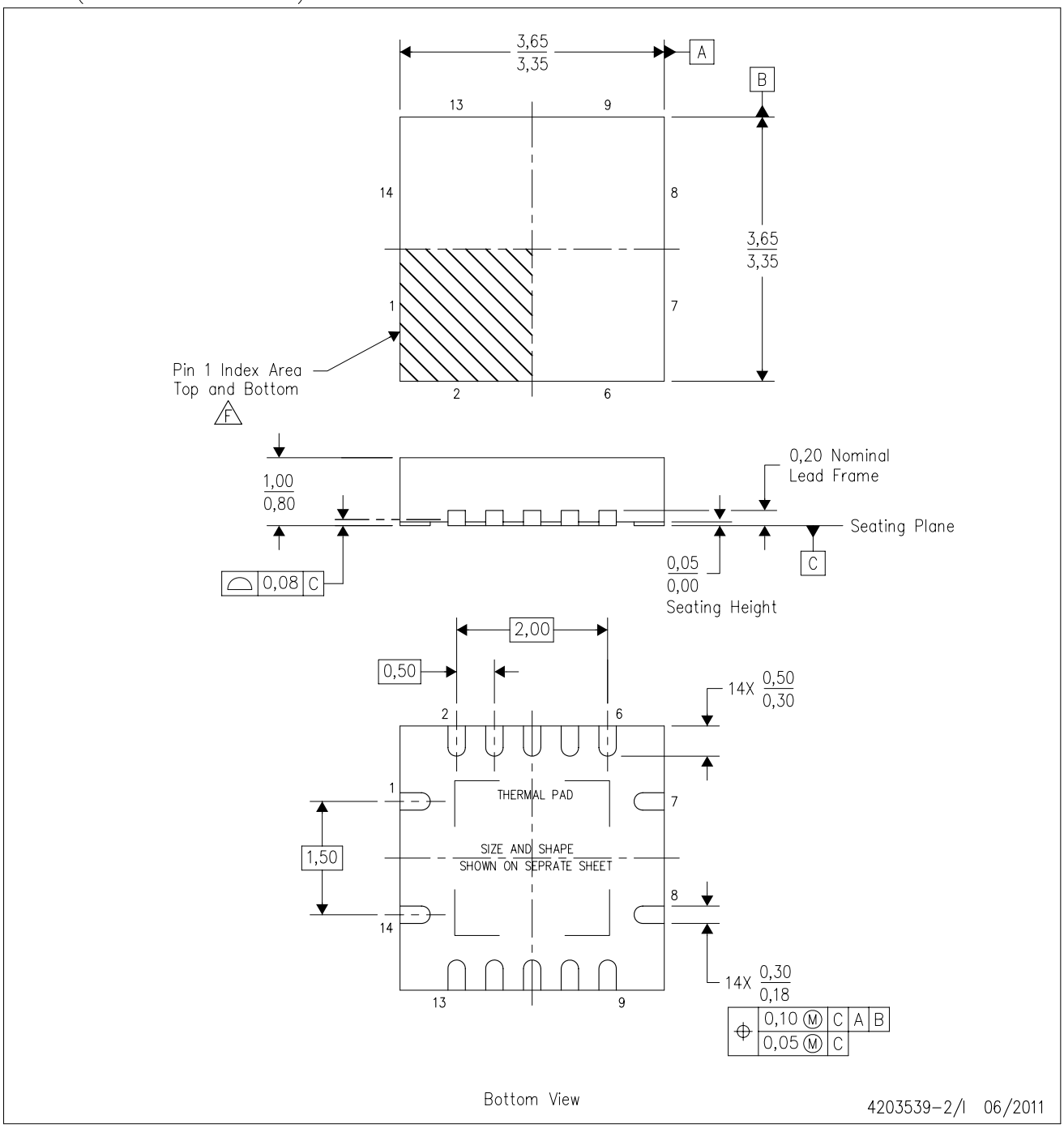
NO. OF TERMINALS **	A		B	
	MIN	MAX	MIN	MAX
20	0.342 (8,69)	0.358 (9,09)	0.307 (7,80)	0.358 (9,09)
28	0.442 (11,23)	0.458 (11,63)	0.406 (10,31)	0.458 (11,63)
44	0.640 (16,26)	0.660 (16,76)	0.495 (12,58)	0.560 (14,22)
52	0.740 (18,78)	0.761 (19,32)	0.495 (12,58)	0.560 (14,22)
68	0.938 (23,83)	0.962 (24,43)	0.850 (21,6)	0.858 (21,8)
84	1.141 (28,99)	1.165 (29,59)	1.047 (26,6)	1.063 (27,0)



4040140/D 01/11

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a metal lid.
D. Falls within JEDEC MS–004

RGY (S–PVQFN–N14) PLASTIC QUAD FLATPACK NO–LEAD



NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. QFN (Quad Flatpack No–Lead) package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
F. Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
G. Package complies to JEDEC MO–241 variation BA.

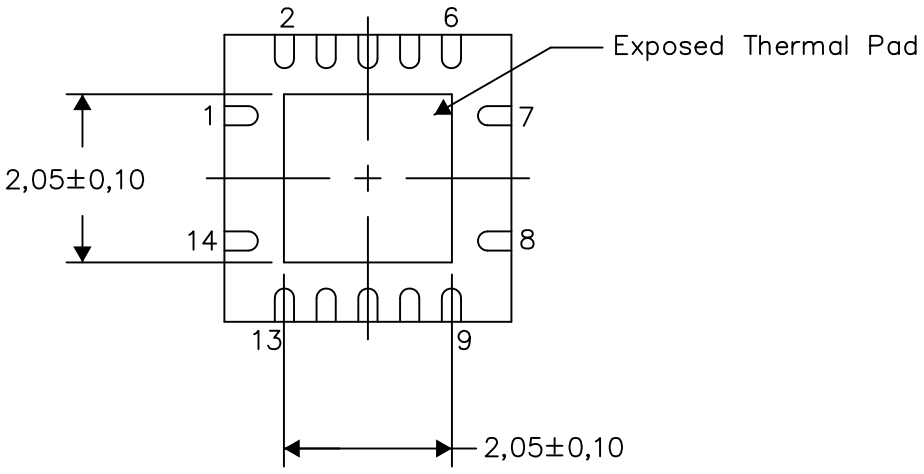
RGY (S–PVQFN–N14) PLASTIC QUAD FLATPACK NO–LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No–Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



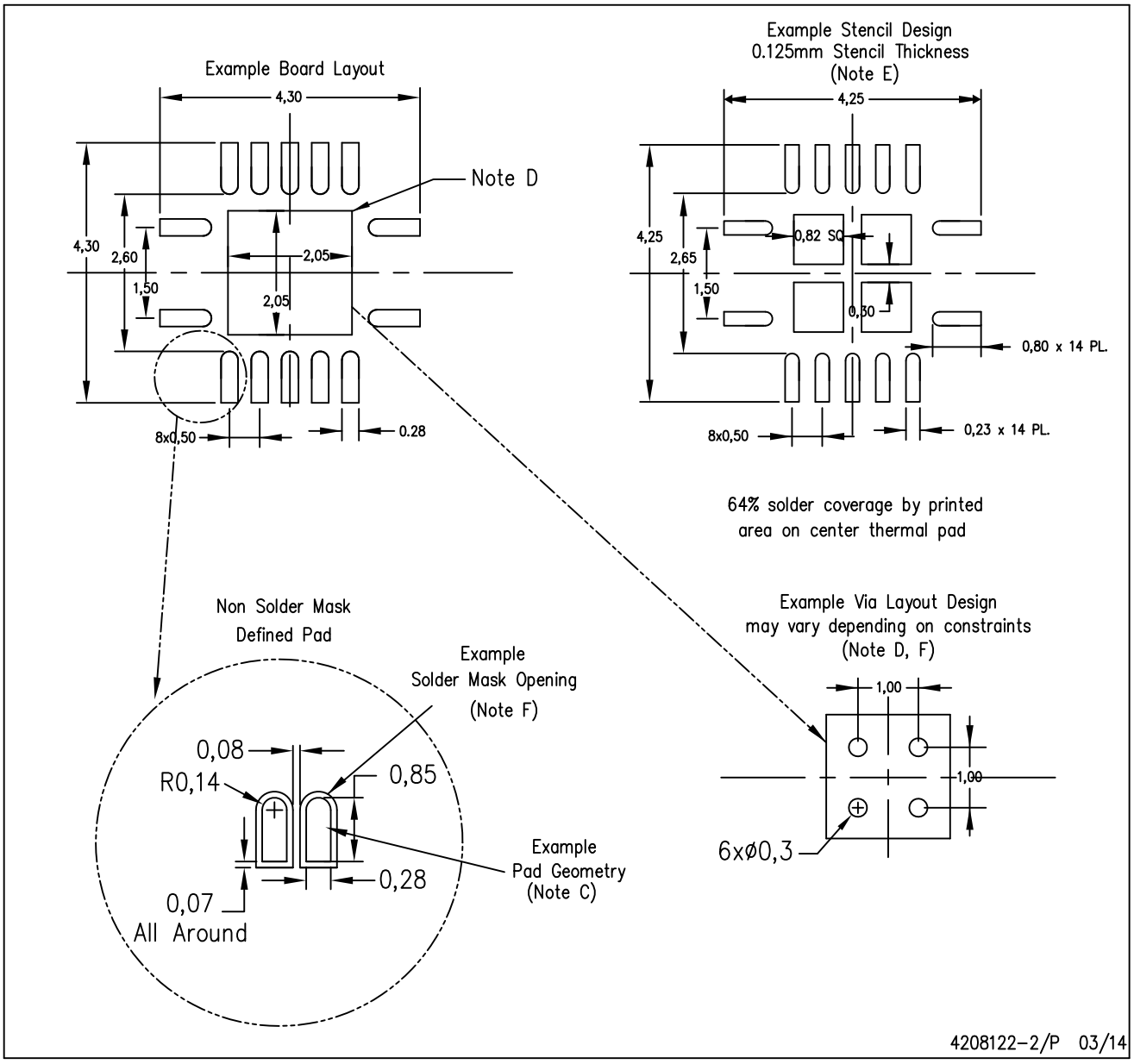
Bottom View

Exposed Thermal Pad Dimensions

4206353–2/P 03/14

NOTE: All linear dimensions are in millimeters

RGY (S–PVQFN–N14) PLASTIC QUAD FLATPACK NO–LEAD

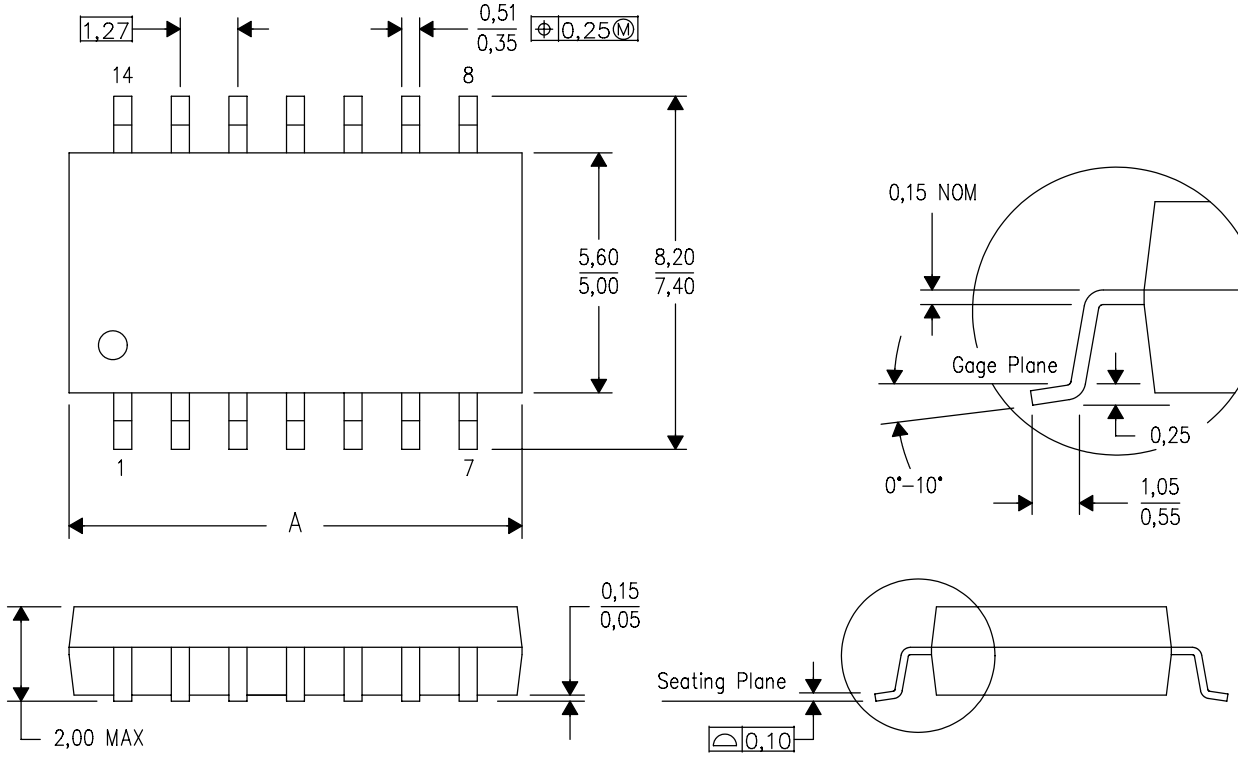


NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat–Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http: //www.ti.com>.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

MECHANICAL DATA

NS (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14-PINS SHOWN

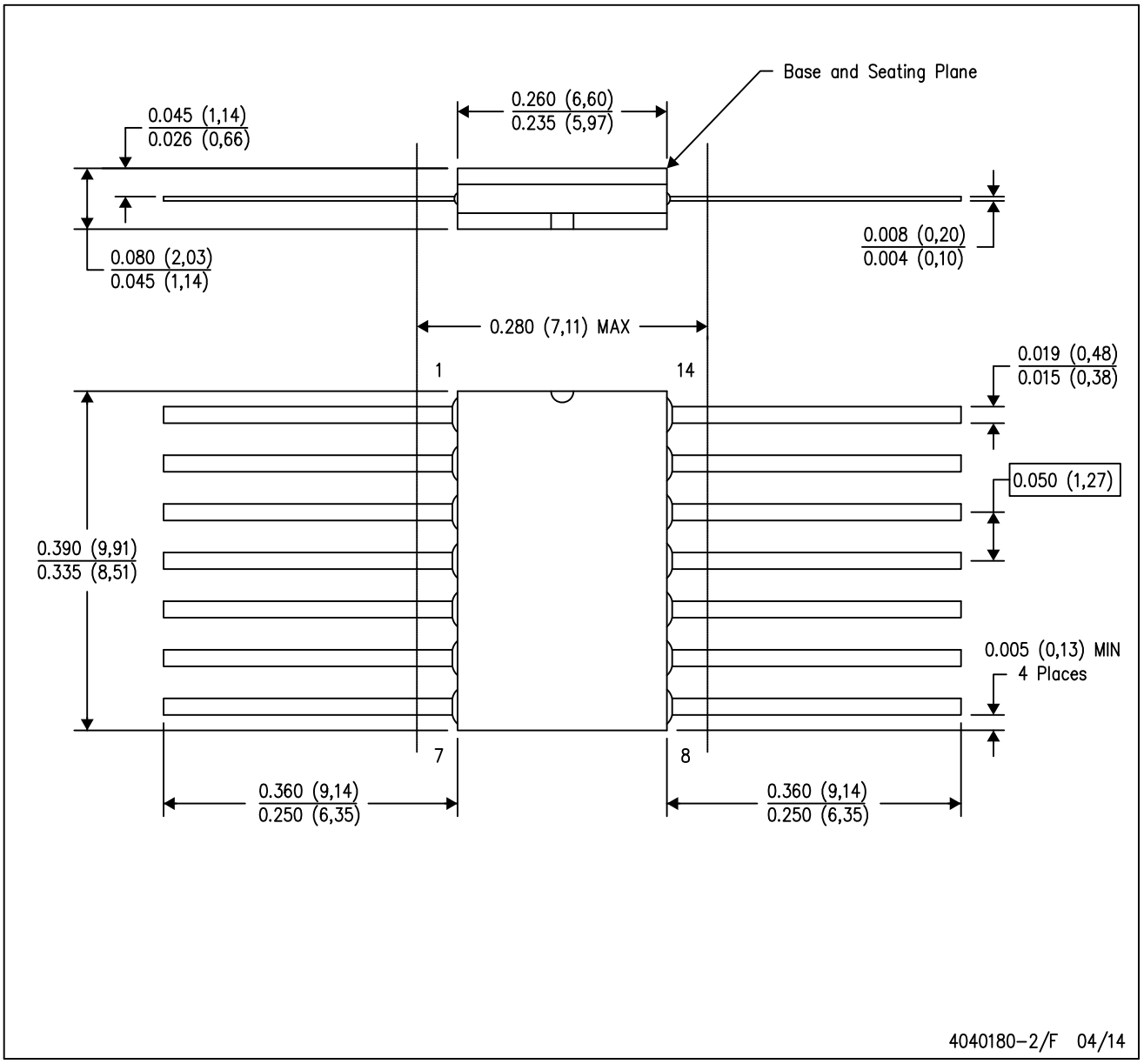


DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

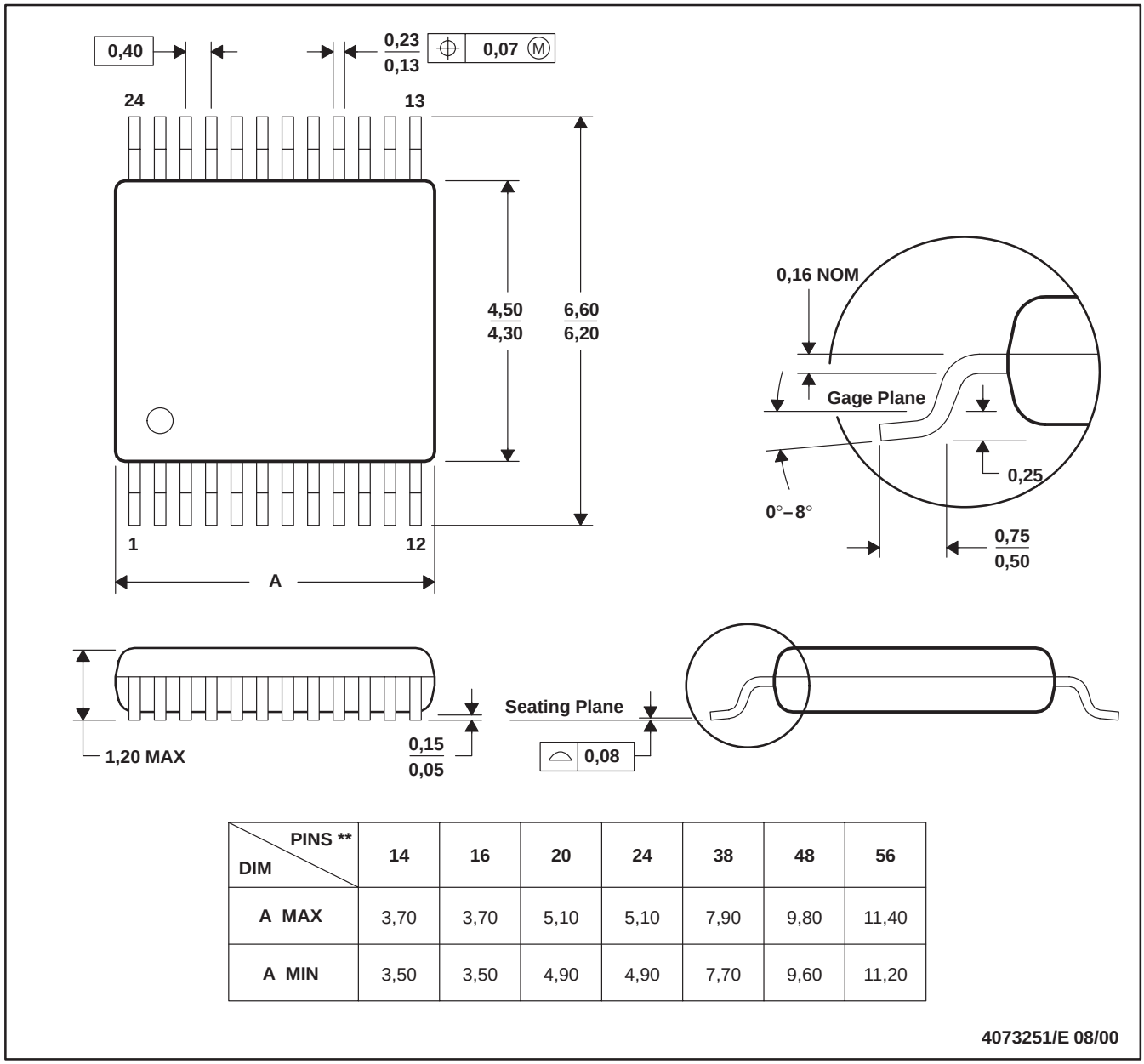
W (R–GDFP–F14) CERAMIC DUAL FLATPACK



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only.
E. Falls within MIL STD 1835 GDFP1–F14

DGV (R-PDSO-G)** **PLASTIC SMALL-OUTLINE**

24 PINS SHOWN



DIM \ PINS **	14	16	20	24	38	48	56
A MAX	3,70	3,70	5,10	5,10	7,90	9,80	11,40
A MIN	3,50	3,50	4,90	4,90	7,70	9,60	11,20

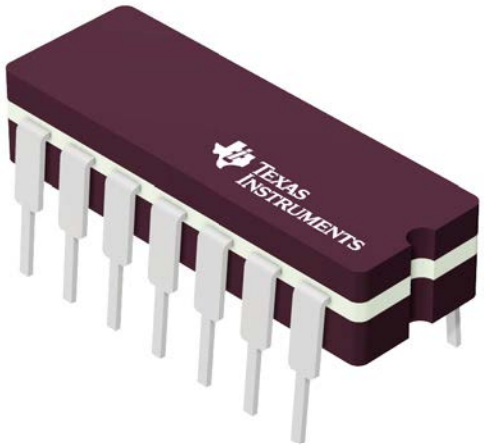
4073251/E 08/00

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
D. Falls within JEDEC: 24/48 Pins – MO-153
14/16/20/56 Pins – MO-194

GENERIC PACKAGE VIEW

J 14 CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

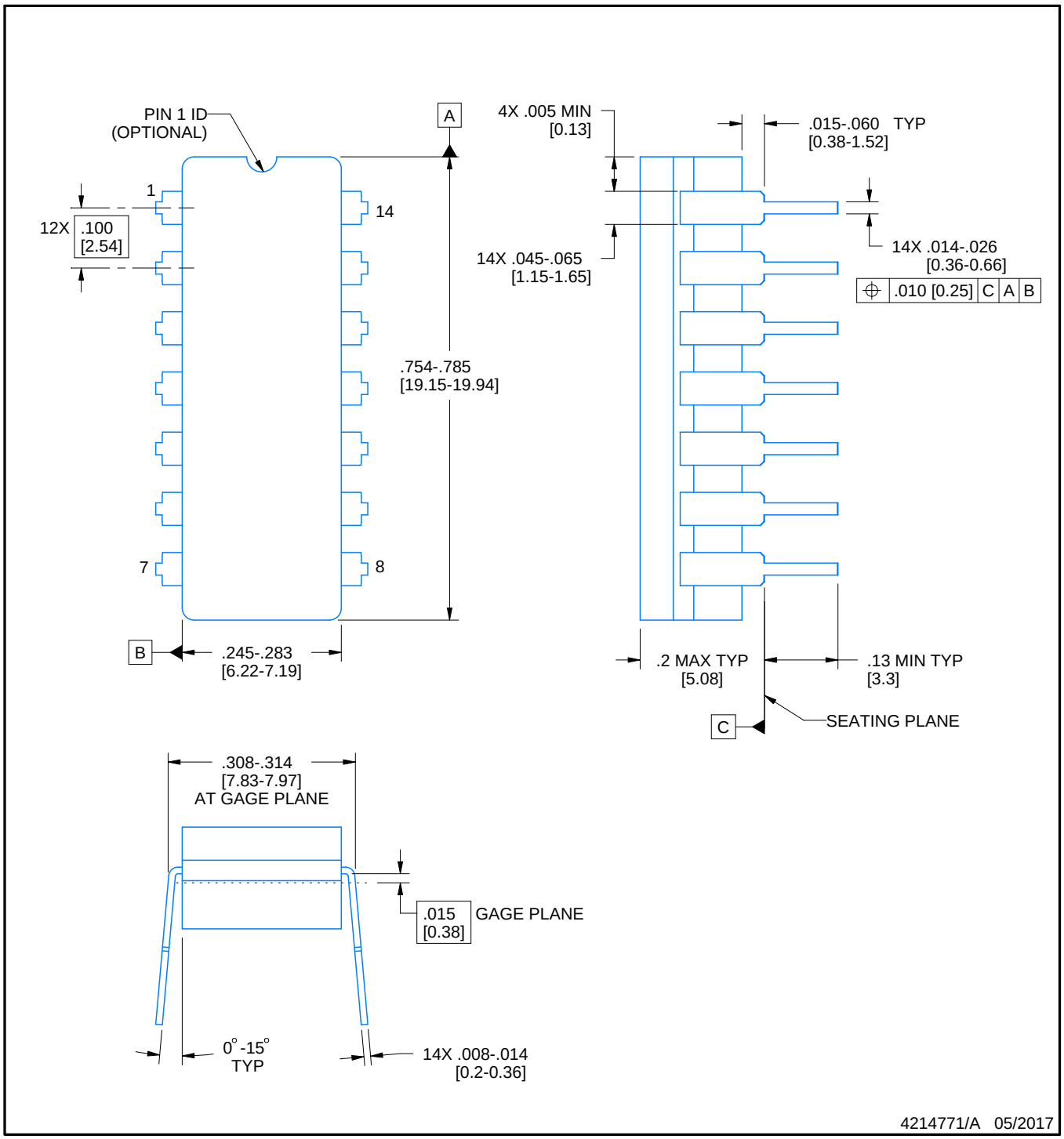
4040083-5/G

PACKAGE OUTLINE

J0014A

CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



NOTES:

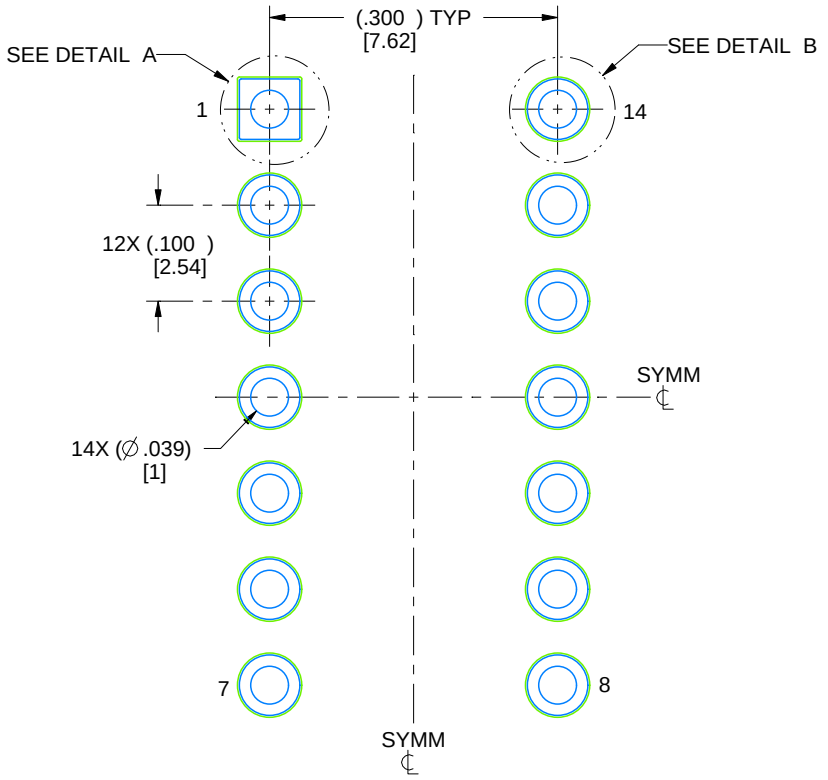
1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package is hermitically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
5. Falls within MIL-STD-1835 and GDIP1-T14.

EXAMPLE BOARD LAYOUT

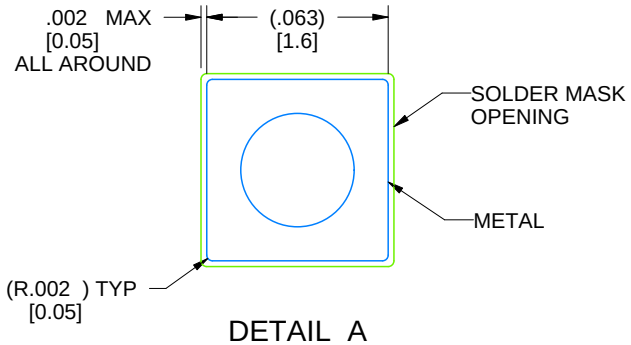
J0014A

CDIP - 5.08 mm max height

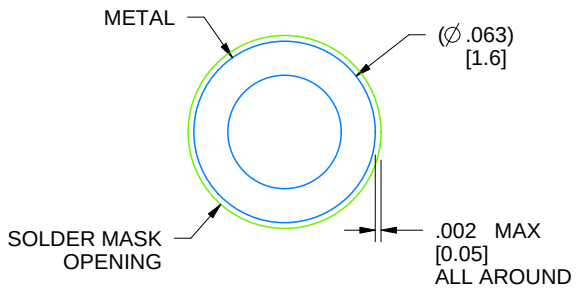
CERAMIC DUAL IN LINE PACKAGE



LAND PATTERN EXAMPLE
NON-SOLDER MASK DEFINED
SCALE: 5X



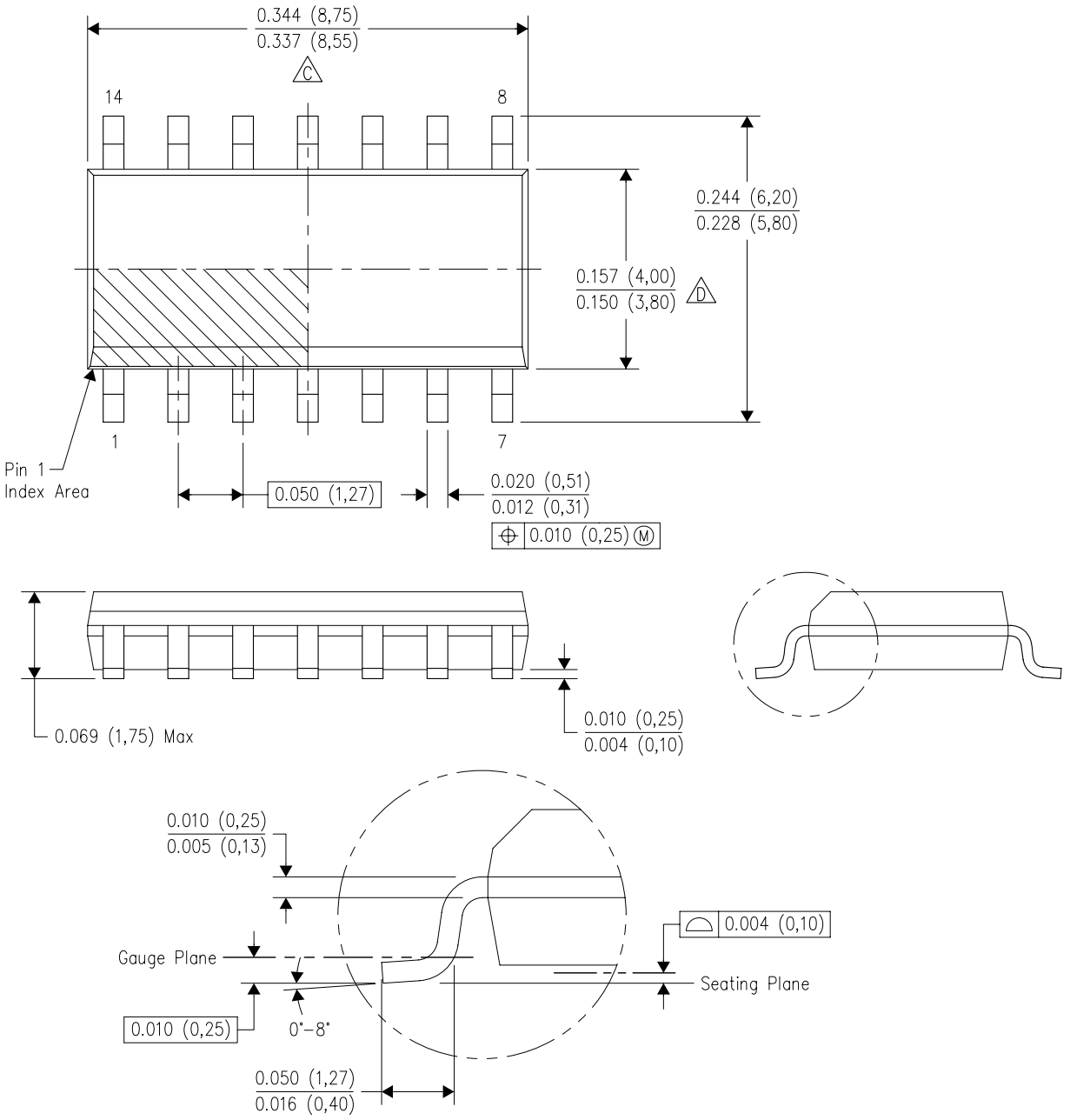
DETAIL A
SCALE: 15X



DETAIL B
13X, SCALE: 15X

4214771/A 05/2017

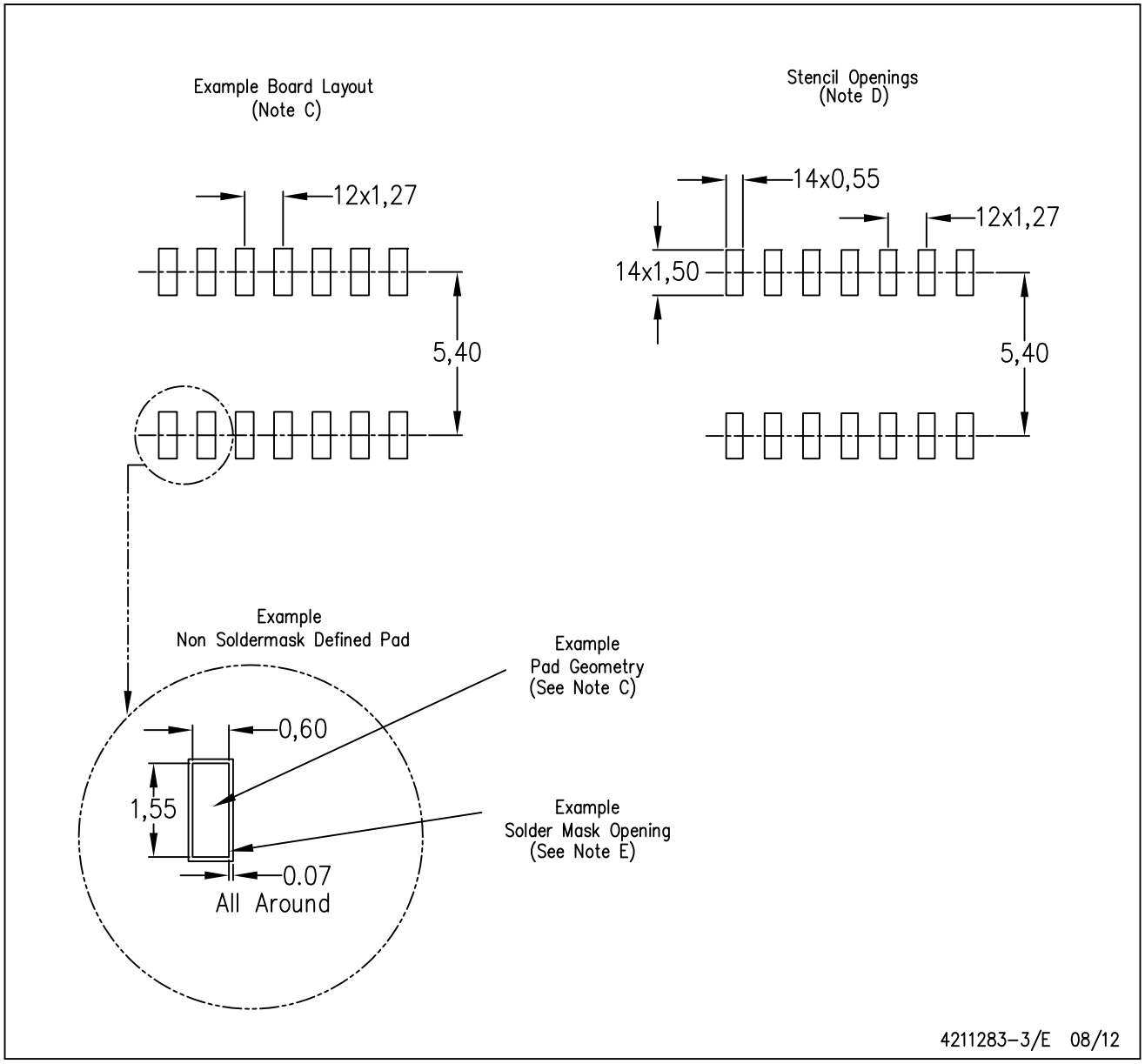
D (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040047–5/M 06/11

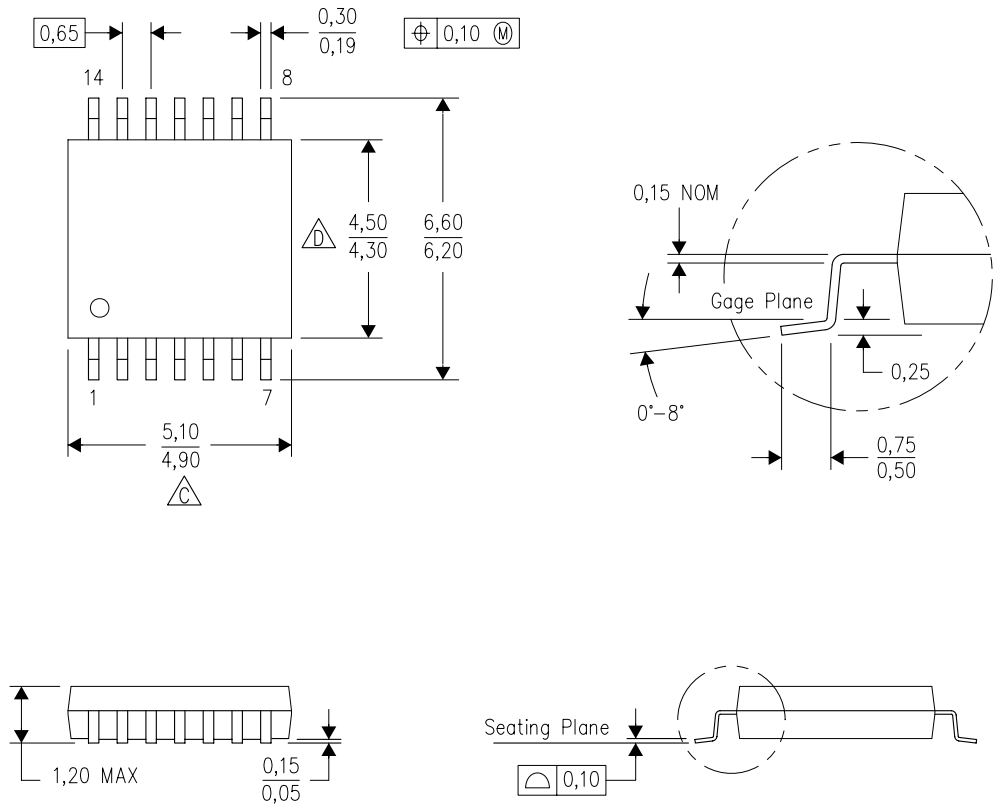
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AB.

D (R–PDSO–G14) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

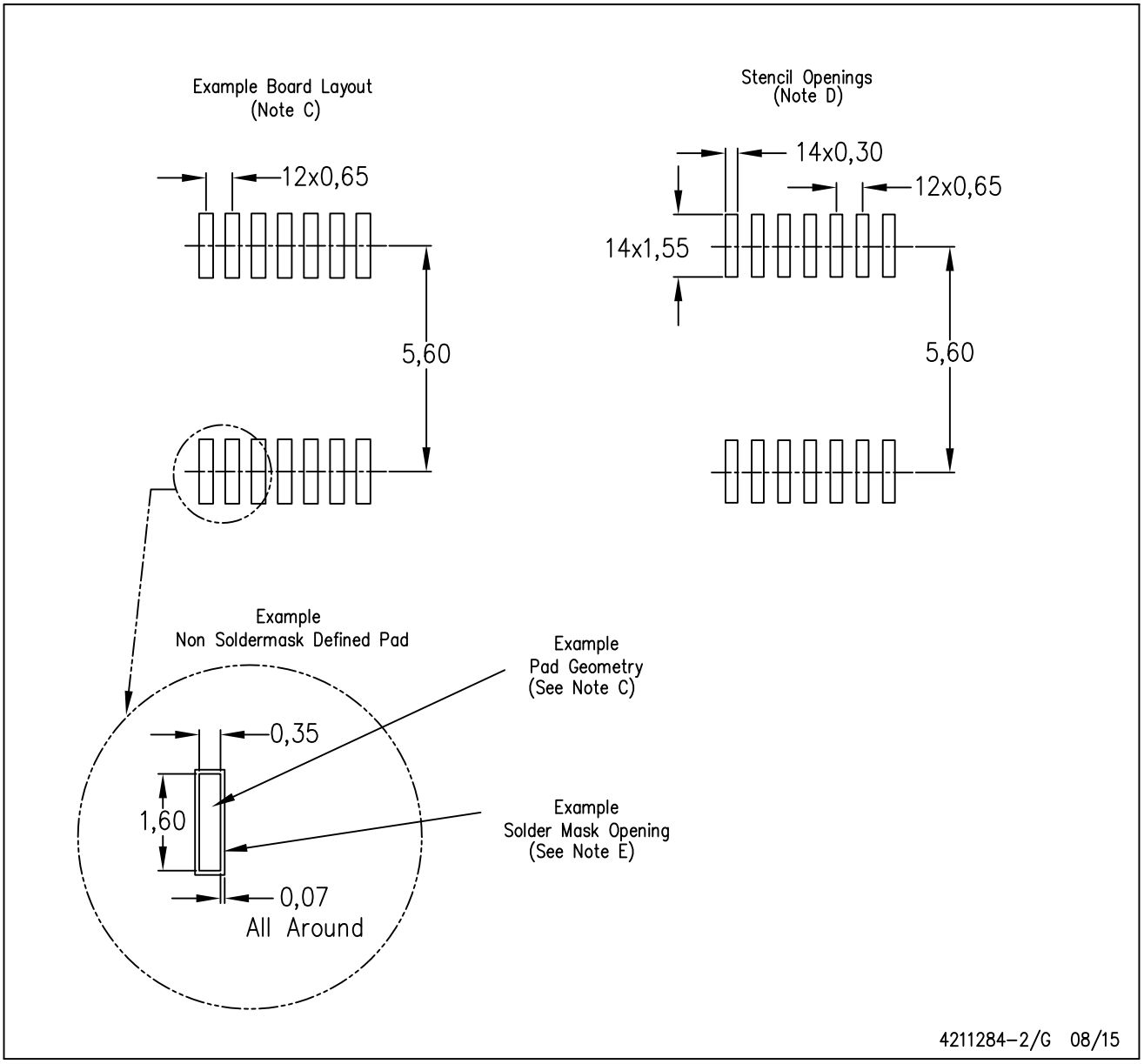
PW (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040064–3/G 02/11

NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
E. Falls within JEDEC MO–153

PW (R–PDSO–G14) PLASTIC SMALL OUTLINE

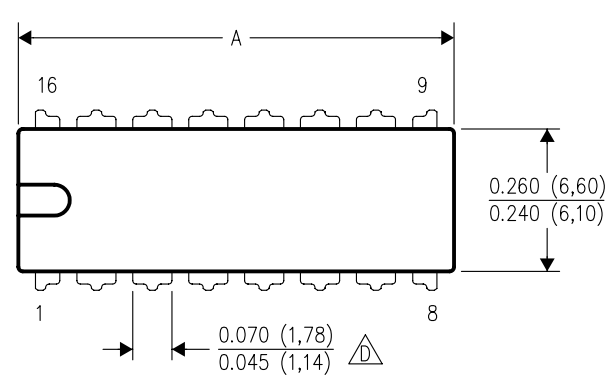


NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

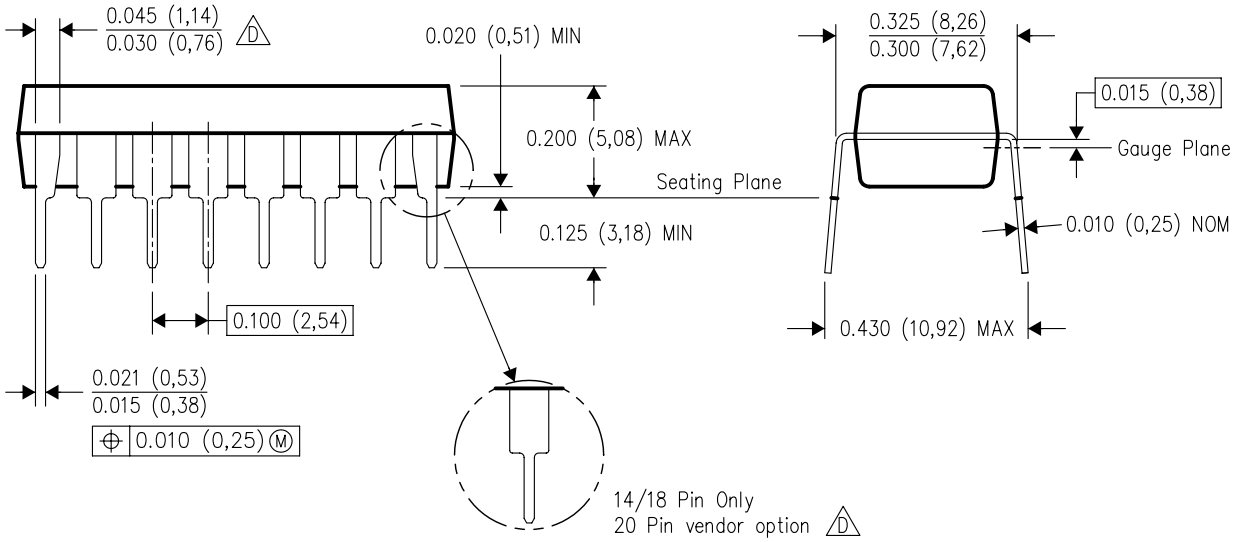
N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN



DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION (C)	AA	BB	AC	AD



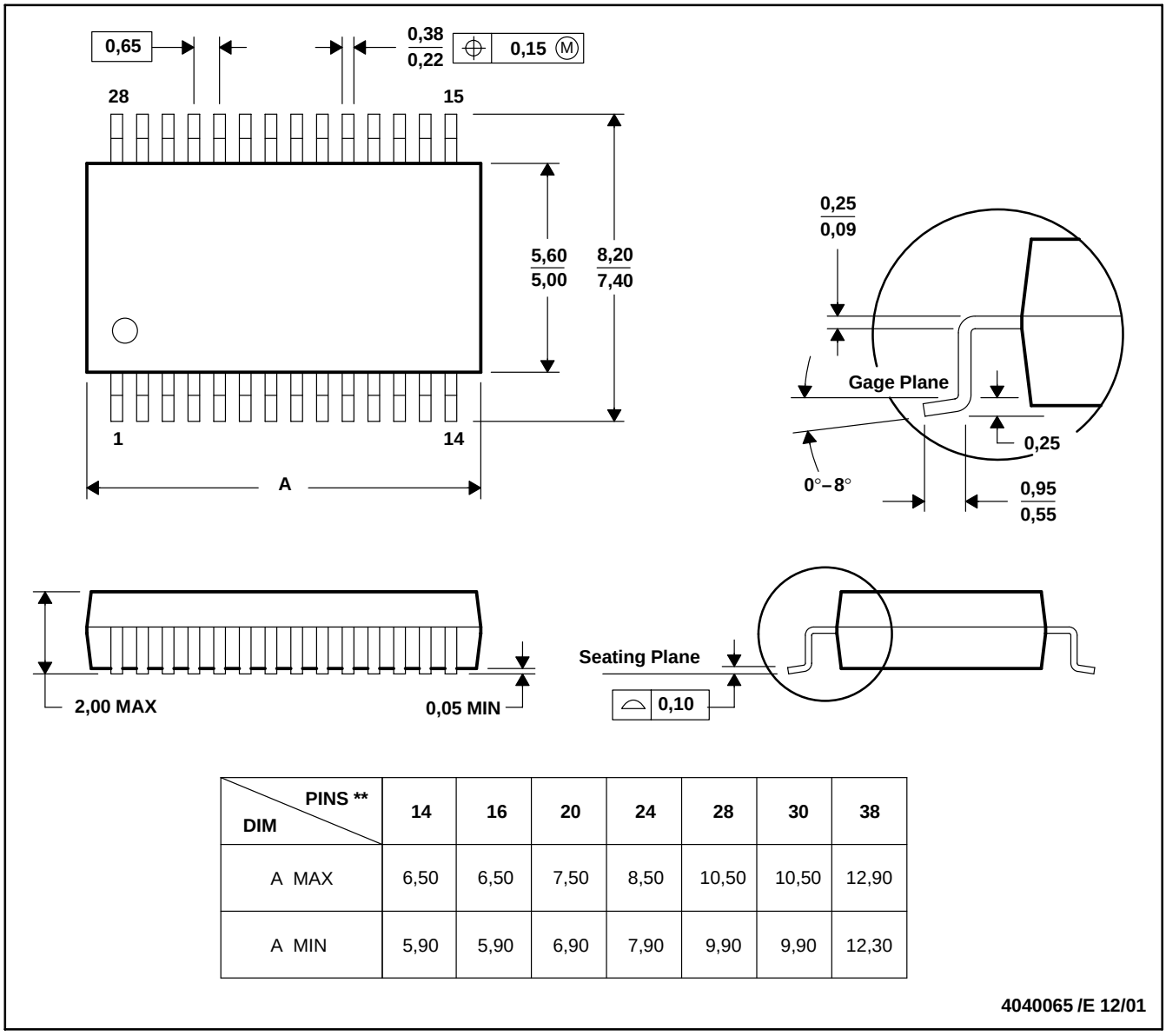
4040049/E 12/2002

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

MSSO002E – JANUARY 1995 – REVISED DECEMBER 2001

DB (R-PDSO-G)** **PLASTIC SMALL-OUTLINE**

28 PINS SHOWN



DIM \ PINS **	14	16	20	24	28	30	38
A MAX	6,50	6,50	7,50	8,50	10,50	10,50	12,90
A MIN	5,90	5,90	6,90	7,90	9,90	9,90	12,30

4040065 /E 12/01

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-150

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